TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX32F, TC74LCX32FK

Low-Voltage Quad 2-Input OR Gate with 5-V Tolerant Inputs and Outputs

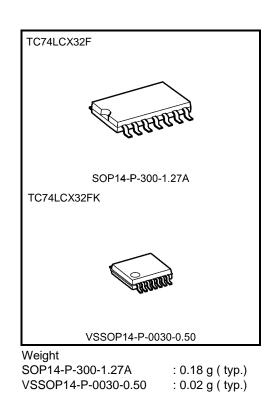
The TC74LCX32 is a high-performance CMOS 2-input OR gate. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low-power dissipation.

The device is designed for low-voltage $(3.3 \text{ V}) \text{ V}_{\text{CC}}$ applications, but it could be used to interface to 5-V supply environment for inputs.

All inputs are equipped with protection circuits against static discharge.

Features

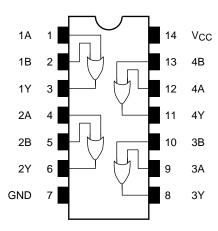
- Low-voltage operation: VCC = 1.65 to 3.6 V
- High-speed operation: $t_{pd} = 5.5 \text{ ns} (\text{max}) (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$
- Output current: $|I_{OH}|/I_{OL} = 24 \text{ mA} (\text{min}) (V_{CC} = 3.0 \text{ V})$
- Available in JEITA SOP, VSSOP (US)
- Power-down protection is provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 32 type



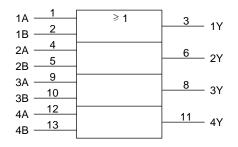
Note: The Electrical Characteristics of V_{CC} = 1.8 ± 0.15 V is only applicable for products which manufactured from January 2009 onward.

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Pin Assignment (top view)



IEC Logic Symbol



Truth Table

| Inp | uts | Outputs |
|-----|-----|---------|
| А | В | Y |
| L | L | L |
| L | Н | н |
| Н | L | Н |
| Н | Н | Н |

Absolute Maximum Ratings (Note 1)

| Characteristics | Symbol | Rating | Unit |
|------------------------------------|-----------------------------------|-------------------------------------------|------|
| Power supply voltage | Vcc | -0.5 to 7.0 | V |
| DC input voltage | Vin | -0.5 to 7.0 | V |
| | | -0.5 to 7.0 (Note 2) | |
| DC output voltage | Vout | -0.5 to V _{CC} + 0.5 (Note 3) | V |
| Input diode current | lık | -50 | mA |
| Output diode current | ЮК | ±50 (Note 4) | mA |
| DC output current | Ιουτ | ±50 | mA |
| Power dissipation | PD | 180 | mW |
| DC V _{CC} /ground current | I _{CC} /I _{GND} | ±100 | mA |
| Storage temperature | T _{stg} | -65 to 150 | °C |

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: VCC = 0 V

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: VOUT < GND, VOUT > VCC

Operating Ranges (Note 1)

| Characteristics | Symbol Rating | | Unit |
|--------------------------|---------------|-------------------------------|------|
| | Vee | 1.65 to 3.6 | |
| Power supply voltage | Vcc | 1.5 to 3.6 (Note 2) | V |
| Input voltage | VIN | 0 to 5.5 | V |
| Output voltage | Vout | 0 to 5.5 (Note 3) | V |
| Output voltage | | 0 to V _{CC} (Note 4) | |
| | Іон/Іоі | ±24 (Note 5) | mA |
| Output current | IOH/IOL | ±12 (Note 6) | ША |
| Operating temperature | Topr | -40 to 85 | °C |
| Input rise and fall time | dt/dv | 0 to 10 (Note 7) | ns/V |

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

Note 3: VCC = 0 V

Note 4: High or low state

Note 5: VCC = 3.0 to 3.6 V

Note 6: VCC = 2.7 to 3.0 V

Note 7: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V

Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C)

| Characteristi | cs | Symbol | Test Condition Vcc (V) | | Min | Max | Unit | | | |
|-------------------------------------|-------------|--------------------------------------------------|------------------------------------------|---------------------------------------------------------|-------------|-------------------------|-----------------------|----|-----|--|
| | | | _ | | 1.65 to 2.3 | V _{CC} × 0.9 | _ | | | |
| | H-level | | | | 2.3 to 2.7 | 1.7 | _ | | | |
| Input voltage | | | | | 2.7 to 3.6 | 2.0 | | V | | |
| Input voltage | | | | | 1.65 to 2.3 | | V _{CC} × 0.1 | v | | |
| | L-level | VIL | — | | 2.3 to 2.7 | | 0.7 | | | |
| | | | | | 2.7 to 3.6 | | 0.8 | | | |
| | | | | $I_{OH} = -100 \ \mu A$ | 1.65 to 3.6 | V _{CC} -0.2 | | | | |
| | | | | Ioh = -4 mA | 1.65 | 1.05 | | | | |
| | H-level | Vон | VIN = VIH or VIL | Iон = -8 mA | 2.3 | 1.7 | _ | V | | |
| | n-ievei | | | I _{OH} = -12 mA | 2.7 | 2.2 | | | | |
| | | | | Iон = -18 mA | 3.0 | 2.4 | _ | | | |
| O david vertike see | | | | Iон = -24 mA | 3.0 | 2.2 | | | | |
| Output voltage | | | | I _{OL} = 100 μA | 1.65 to 3.6 | | 0.2 | | | |
| | | | | IoL = 4 mA | 1.65 | — | 0.45 | | | |
| | 1.11 | | | I _{OL} = 8 mA | 2.3 | | 0.7 | | | |
| | L-level | L-level VoL VIN = VIL I _{OL} = 12 mA | 2.7 | — | 0.4 | | | | | |
| | | | | IOL = 16 mA | 3.0 | — | 0.4 | | | |
| | | | | I _{OL} = 24 mA | 3.0 | — | 0.55 | | | |
| Input leakage current | | lin | V _{IN} = 0 to 5.5 V | | 1.65 to 3.6 | _ | ±5.0 | μA | | |
| Power-off leakage curr | urrent IOFF | | $V_{IN}/V_{OUT} = 5.5 V$ | | 0 | | 10.0 | μA | | |
| | | | V _{IN} = V _{CC} or GND | | 1.65 to 3.6 | | 10.0 | | | |
| Quiescent supply curre | | Icc | VIN = 3.6 to 5.5 V | | 1.65 to 3.6 | | ±10.0 | μA | | |
| Increase in I _{CC} per inp | ut | ∆lcc | $V_{IH} = V_{CC} - 0.6 V$ (pe | V _{IH} = V _{CC} – 0.6 V (per 1 input) | | per 1 input) 2.7 to 3.6 | | | 500 | |



AC Characteristics (Ta = -40 to $85^{\circ}C$)

| Characteristics | Characteristics Symbol Test Condition | | | Min | Max | Unit |
|--------------------------------|---------------------------------------|--------------------|-------------------------------|-----|------|------|
| | | | Vcc (V) | | | |
| | | | 1.8 ± 0.15 | _ | 20.0 | |
| Propagation delay time | tpLH tpHL | Figure 1, Figure 2 | 2.5 ± 0.2 | — | 7.2 | 20 |
| | | | 2.7 | _ | 6.2 | ns |
| | | | $\textbf{3.3}\pm\textbf{0.3}$ | 1.5 | 5.5 | |
| Output to output closure tosLH | | (0.1=1=) | 2.7 | | | 20 |
| Output to output skew | t _{osHL} | (Note) | $\textbf{3.3}\pm\textbf{0.3}$ | _ | 1.0 | ns |

Note: Parameter guaranteed by design.

(tosLH = |tpLHm - tpLHn|, tosHL = |tpHLm - tpHLn|)

Dynamic Switching Characteristics (Ta = 25°C, input: tr = tf = 2.5 ns, CL = 50 pF, RL = 500 Ω)

| Characteristics | Symbol | Test Condition | V _{CC} (V) | Тур. | Unit |
|---------------------------------------|--------|------------------------------------------------|---------------------|------|------|
| Quiet output maximum dynamic VOL | Volp | $V_{IH}=3.3~V,~V_{IL}=0~V$ | 3.3 | 0.8 | V |
| Quiet output minimum dynamic V_{OL} | Volv | $V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ | 3.3 | 0.8 | V |

Capacitive Characteristics ($Ta = 25^{\circ}C$)

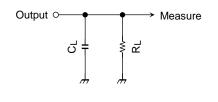
| Characteristics | Symbol | Test Condition | | Тур. | Unit |
|-------------------------------|--------|---------------------|-----|------|------|
| Input capacitance | CIN | _ | 3.3 | 7 | pF |
| Output capacitance | COUT | _ | 0 | 8 | pF |
| Power dissipation capacitance | Cpd | fin = 10 MHz (Note) | 3.3 | 25 | pF |

Note: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: ICC (opr) = CPD · VCC · fIN + ICC/4 (per gate)

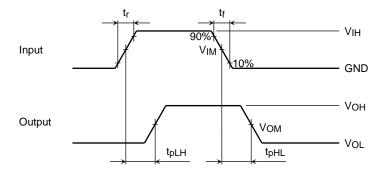
AC Test Circuit

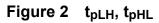
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AC Waveform





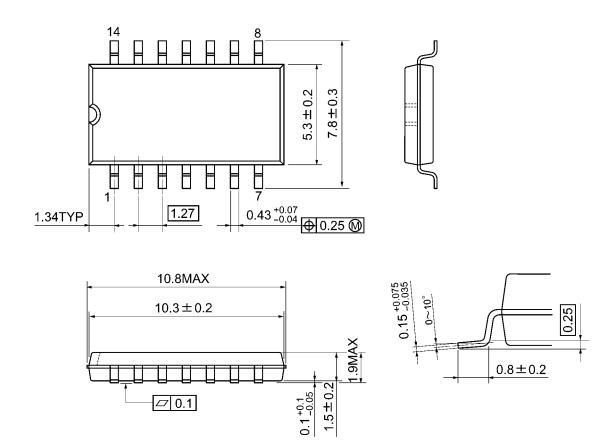
| | | | V _{CC} | |
|--------|---------------------------------|----------------------|----------------------|-----------------------|
| | Symbol | 3.3 ± 0.3 V 2.7 V | $2.5\pm0.2~\text{V}$ | $1.8\pm0.15~\text{V}$ |
| Input | VIH | 2.7 V | Vcc | Vcc |
| | VIM | 1.5 V | V _{CC} /2 | V _{CC} /2 |
| | t _r , t _f | 2.5 ns | 2.0 ns | 2.0 ns |
| Output | Vom | 1.5 V | V _{OH} /2 | V _{OH} /2 |
| Load | CL | 50 pF | 30 pF | 30 pF |
| | RL | 500 Ω | 500 Ω | 1 kΩ |



Package Dimensions

SOP14-P-300-1.27A

Unit: mm



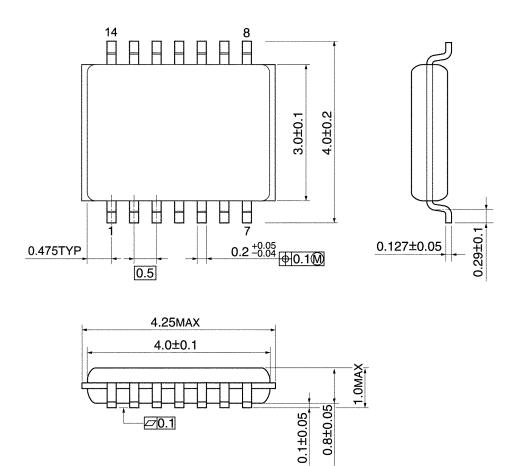
Weight: 0.18 g (typ.)



Package Dimensions

VSSOP14-P-0030-0.50

Unit: mm



Weight: 0.02 g (typ.)

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